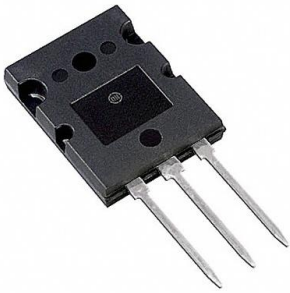


# MJL3281A Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



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DiGi Electronics Part Number	MJL3281A-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	MJL3281A
Description	TRANS NPN 260V 15A TO264
Detailed Description	Bipolar (BJT) Transistor NPN 260 V 15 A 30MHz 200 W Through Hole TO-264



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

MJL3281A

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

260 V

Current - Collector Cutoff (Max):

50µA (ICBO)

Power - Max:

200 W

Operating Temperature:

-65°C ~ 150°C (TJ)

Package / Case:

TO-264-3, TO-264AA

Base Product Number:

MJL32

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

15 A

Vce Saturation (Max) @ Ib, Ic:

3V @ 1A, 10A

DC Current Gain (hFE) (Min) @ Ic, Vce:

75 @ 5A, 5V

Frequency - Transition:

30MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-264

## Environmental & Export classification

RoHS Status:

RoHS non-compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

# Complementary Bipolar Power Transistors

## MJL3281A (NPN) MJL1302A (PNP)

**15 AMPERES  
COMPLEMENTARY  
SILICON POWER  
TRANSISTORS  
260 VOLTS  
200 WATTS**

### Features

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 5 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency
- These Devices are Pb-Free and are RoHS Compliant\*

### Benefits

- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwidth

### Applications

- High-End Consumer Audio Products
  - ◆ Home Amplifiers
  - ◆ Home Receivers
- Professional Audio Amplifiers
  - ◆ Theater and Stadium Sound Systems
  - ◆ Public Address Systems (PAs)

### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

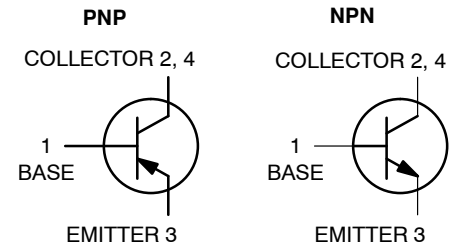
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	260	Vdc
Collector-Base Voltage	$V_{CBO}$	260	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	$V_{CEX}$	260	Vdc
Collector Current - Continuous	$I_C$	15	Adc
Collector Current - Peak (Note 1)	$I_{CM}$	25	Adc
Base Current - Continuous	$I_B$	1.5	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate Above $25^\circ\text{C}$	$P_D$	200 1.43	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	- 65 to +150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

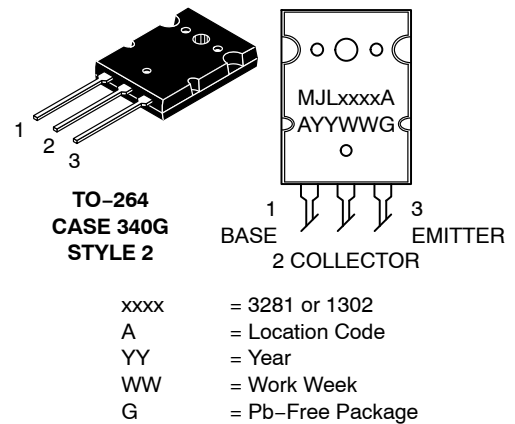
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.625	$^\circ\text{C}/\text{W}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.



### MARKING DIAGRAM



### ORDERING INFORMATION

Device	Package	Shipping
MJL3281AG	TO-264 (Pb-Free)	25 Units/Rail
MJL1302AG	TO-264 (Pb-Free)	25 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**MJL3281A (NPN) MJL1302A (PNP)****ELECTRICAL CHARACTERISTICS** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Sustaining Voltage ( $I_C = 100\text{ mA}$ , $I_B = 0$ )	$V_{CEO(sus)}$	260	–	Vdc
Collector Cutoff Current ( $V_{CB} = 260\text{ Vdc}$ , $I_E = 0$ )	$I_{CBO}$	–	50	$\mu\text{A}$
Emitter Cutoff Current ( $V_{EB} = 5\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	5	$\mu\text{A}$
<b>SECOND BREAKDOWN</b>				
Second Breakdown Collector with Base Forward Biased ( $V_{CE} = 50\text{ Vdc}$ , $t = 1\text{ s}$ (non-repetitive)) ( $V_{CE} = 100\text{ Vdc}$ , $t = 1\text{ s}$ (non-repetitive))	$I_{S/b}$	4 1	– –	A
<b>ON CHARACTERISTICS</b>				
DC Current Gain ( $I_C = 500\text{ mA}$ , $V_{CE} = 5\text{ Vdc}$ ) ( $I_C = 1\text{ A}$ , $V_{CE} = 5\text{ Vdc}$ ) ( $I_C = 3\text{ A}$ , $V_{CE} = 5\text{ Vdc}$ ) ( $I_C = 5\text{ A}$ , $V_{CE} = 5\text{ Vdc}$ ) ( $I_C = 8\text{ A}$ , $V_{CE} = 5\text{ Vdc}$ )	$h_{FE}$	75 75 75 75 45	150 150 150 150 –	
Collector-Emitter Saturation Voltage ( $I_C = 10\text{ A}$ , $I_B = 1\text{ A}$ )	$V_{CE(sat)}$	–	3	Vdc
<b>DYNAMIC CHARACTERISTICS</b>				
Current-Gain - Bandwidth Product ( $I_C = 1\text{ A}$ , $V_{CE} = 5\text{ Vdc}$ , $f_{test} = 1\text{ MHz}$ )	$f_T$	30	–	MHz
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f_{test} = 1\text{ MHz}$ )	$C_{ob}$	–	600	pF

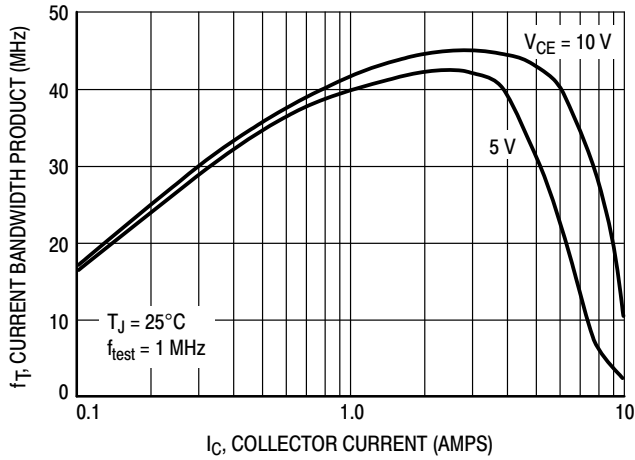
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be

indicated by the Electrical Characteristics if operated under different conditions.

**MJL3281A (NPN) MJL1302A (PNP)**

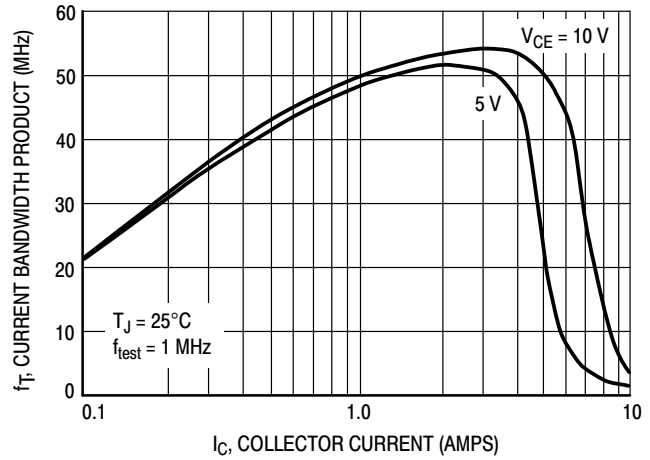
**TYPICAL CHARACTERISTICS**

**PNP MJL1302A**



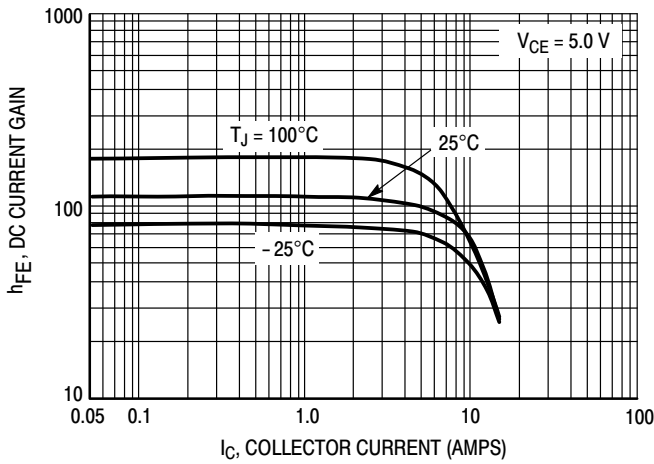
**Figure 1. Typical Current Gain Bandwidth Product**

**NPN MJL3281A**



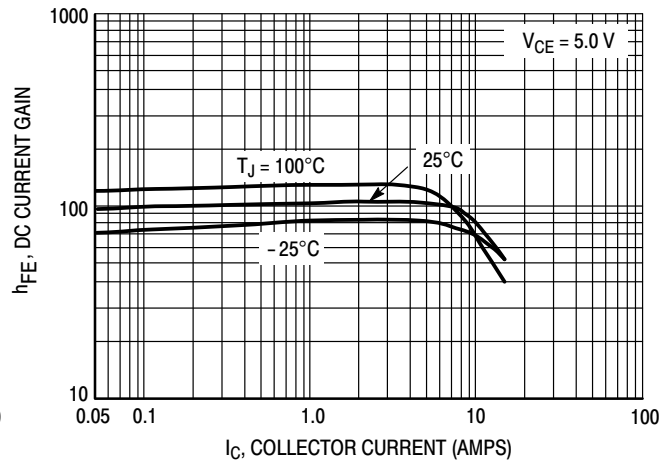
**Figure 2. Typical Current Gain Bandwidth Product**

**PNP MJL1302A**



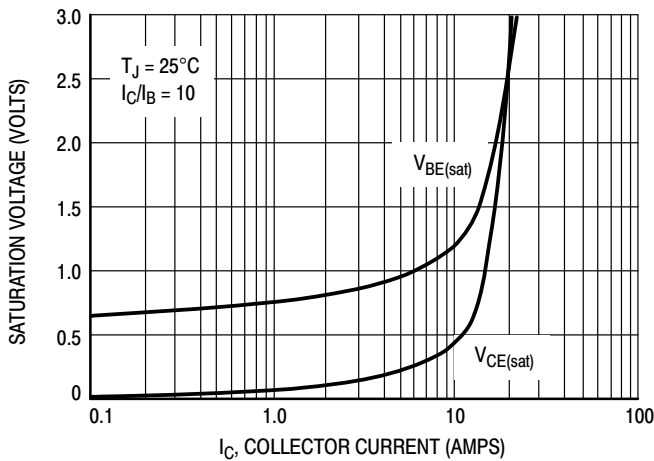
**Figure 3. DC Current Gain**

**NPN MJL3281A**



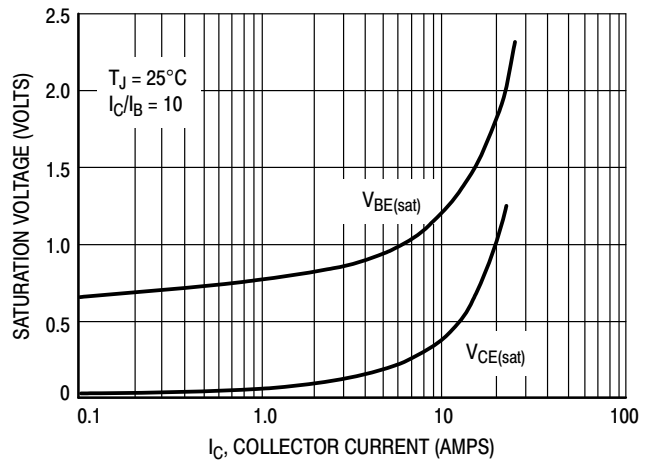
**Figure 4. DC Current Gain**

**PNP MJL1302A**



**Figure 5. Typical Saturation Voltages**

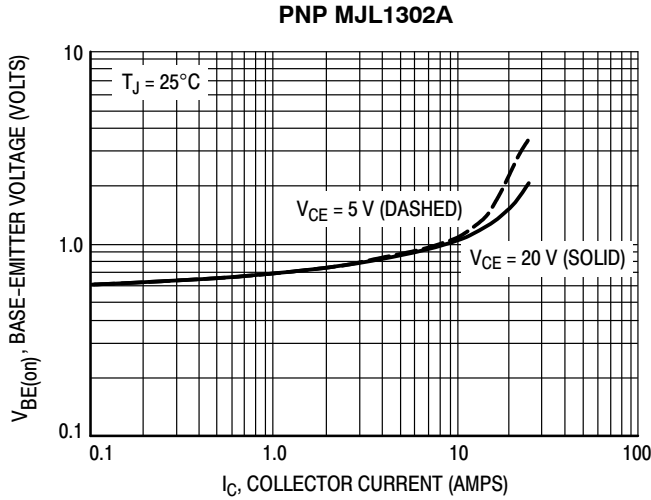
**NPN MJL3281A**



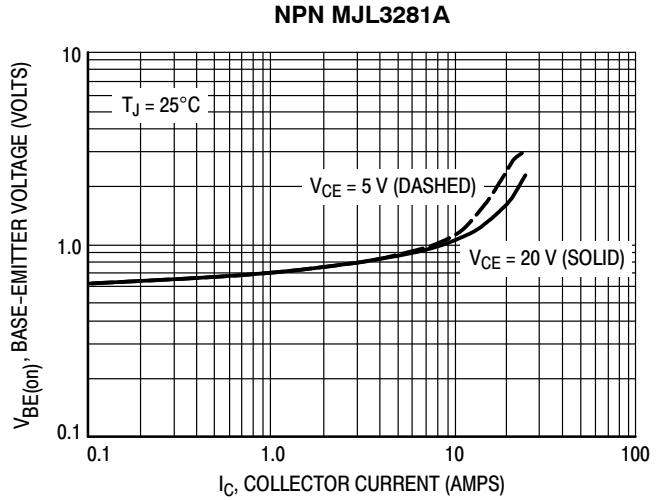
**Figure 6. Typical Saturation Voltages**

**MJL3281A (NPN) MJL1302A (PNP)**

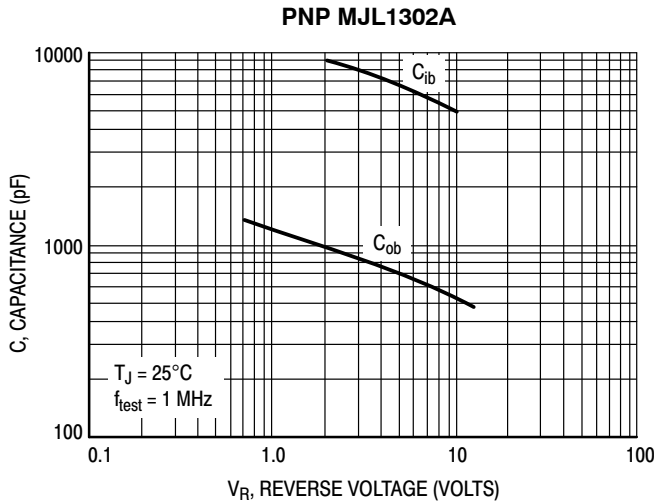
**TYPICAL CHARACTERISTICS**



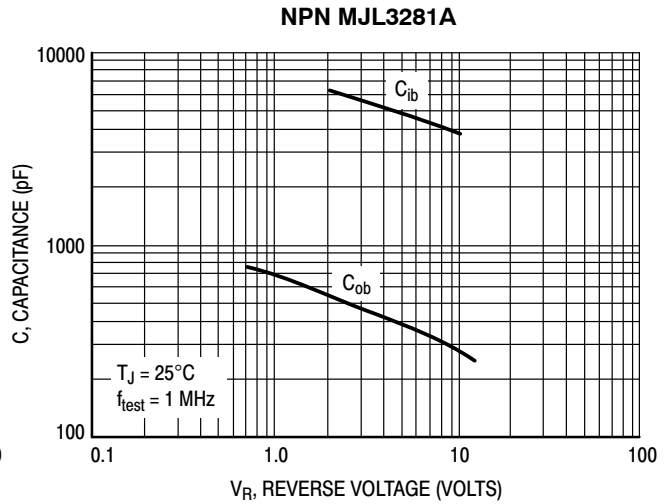
**Figure 7. Typical Base-Emitter Voltage**



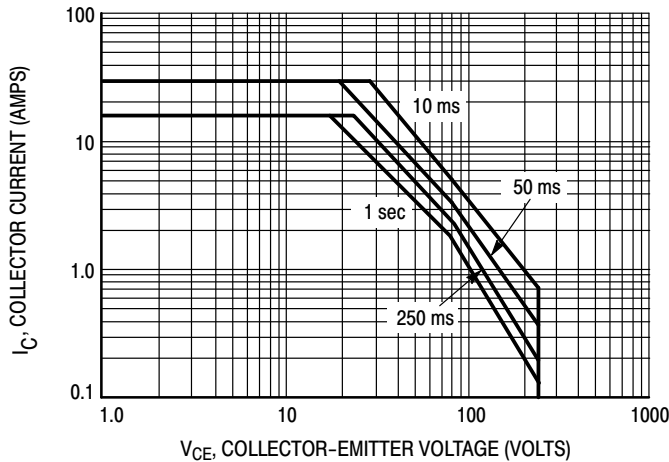
**Figure 8. Typical Base-Emitter Voltage**



**Figure 9. MJL1302A Typical Capacitance**



**Figure 10. MJL3281A Typical Capacitance**



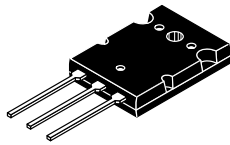
**Figure 11. Active Region Safe Operating Area**

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 11 is based on  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.



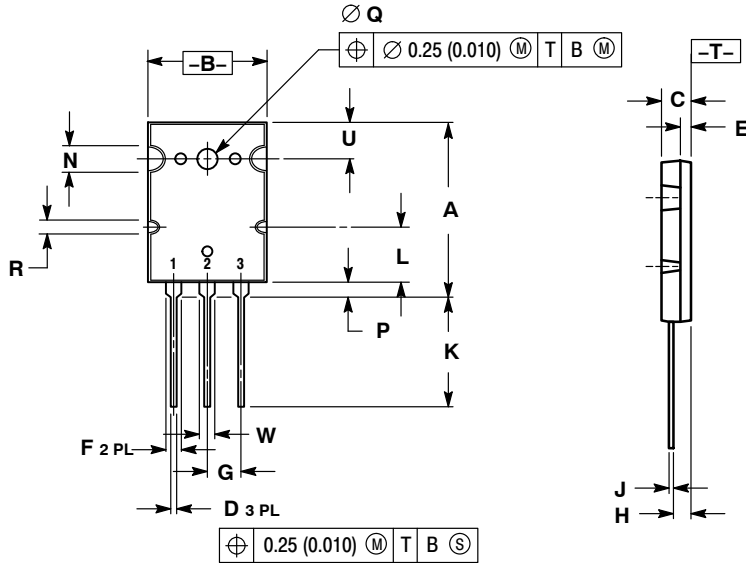
**MECHANICAL CASE OUTLINE  
PACKAGE DIMENSIONS**



**TO-3BPL (TO-264)**  
CASE 340G-02  
ISSUE J

DATE 17 DEC 2004

SCALE 1:2

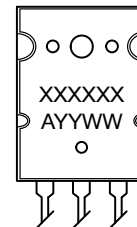


- NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	28.0	29.0	1.102	1.142
B	19.3	20.3	0.760	0.800
C	4.7	5.3	0.185	0.209
D	0.93	1.48	0.037	0.058
E	1.9	2.1	0.075	0.083
F	2.2	2.4	0.087	0.102
G	5.45 BSC		0.215 BSC	
H	2.6	3.0	0.102	0.118
J	0.43	0.78	0.017	0.031
K	17.6	18.8	0.693	0.740
L	11.2 REF		0.411 REF	
N	4.35 REF		0.172 REF	
P	2.2	2.6	0.087	0.102
Q	3.1	3.5	0.122	0.137
R	2.25 REF		0.089 REF	
U	6.3 REF		0.248 REF	
W	2.8	3.2	0.110	0.125

**GENERIC MARKING DIAGRAM\***

- |  |   |  |  |   |
|--|---|--|--|---|
| STYLE 1:<br>PIN 1. GATE<br>2. DRAIN<br>3. SOURCE | STYLE 2:<br>PIN 1. BASE<br>2. COLLECTOR<br>3. EMITTER | STYLE 3:<br>PIN 1. GATE<br>2. SOURCE<br>3. DRAIN | STYLE 4:<br>PIN 1. DRAIN<br>2. SOURCE<br>3. GATE | STYLE 5:<br>PIN 1. GATE<br>2. COLLECTOR<br>3. EMITTER |
|--|---|--|--|---|



- XXXXXX = Specific Device Code  
A = Location Code  
YY = Year  
WW = Work Week

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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